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STATEMENT BY APPLICANT					APPLICANT: Cesare CLEMENTI et al.			S 638	
Sheet 1 of 1					GROUP ART UNIT: Unassigned EXAM			INER: Unassigned	20/
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Examiner's Initials#	Cite No.	U.S. Patent Document				Name of Patentee or Applicant of C	Date of Publication or of issu		
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